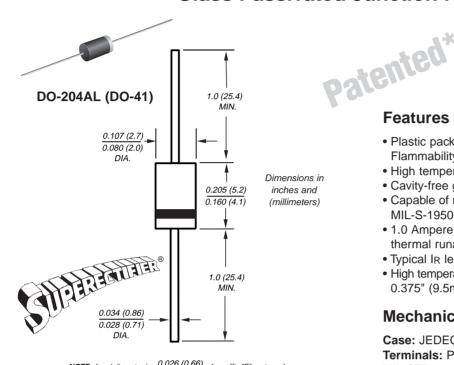


Vishay Semiconductors formerly General Semiconductor

Glass Passivated Junction Rectifiers

Reverse Voltage 50 to 1600V Forward Current 1.0A



0.026 (0.66) 0.023 (0.58) NOTE: Lead diameter is for suffix "E" part numbers

*Glass-plastic encapsulation technique is covered by Patent No. 3,996,602, and brazed-lead assembly by Patent No. 3,930,306

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- · Cavity-free glass passivated junction
- · Capable of meeting environmental standards of MIL-S-19500
- 1.0 Ampere operation at T_A = 75°C and 55°C with no thermal runaway
- Typical IR less than 0.1μA
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-204AL, molded plastic over glass body

Terminals: Plated axial leads, solderable per

MIL-STD-750. Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any Weight: 0.012 oz., 0.3 g

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Α	В	D	G	J	K	M	ı	N C	2	Т	٧	W	Υ	Unit
Maximum repetitive peak reverse voltage	VRRM	50 to 1600V (See Fig. 5)									V					
Maximum average forward rectified current 0.375" (9.5mm) lead length (See fig. 1)	I _{F(AV)}	1.0								А						
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30						25						А		
Maximum full load reverse current, full cycle average, 0.375" (9.5mm) lead lengths at T _A = 75°C	I _{R(AV)}	30						μА								
Typical thermal resistance (Note 1)	RθJA	55							°C/W							
Operating junction and storage temperature range	TJ, TSTG		-65 to +175					-65 to +150						°C		

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter		Symbol	Α	В	D	G	J	K	М	N	Q	Т	٧	w	Υ	Unit
Maximum instantaneous forward voltage at 1.0A		VF	1.1						1	.2		1.3				V
Maximum DC reverse current at rated DC blocking voltage	T _A = 25°C T _A = 125°C	IR	5.0 50										μА			
Typical reverse recovery time at IF = 0.5A, IR = 1.0A, Irr = 0.25A		t _{rr}	3.0										μs			
Typical junction capacitance at 4.0V, 1MHz		CJ		8.0				7.0				5.0				pF

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

GP10A thru GP10Y

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Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)



www.vishay.com Document Number 88637 2 5-Mar-02